

RB520SM5-30

Schottky Diode

FEATURE

- Low current Rectification
- Low reverse current
- SOD523 Thin SMD package
- RoHS compliant / Green EMC
- Matte Tin (Sn) Lead finish
- Cathode Band / Device marking

SOD-523



Schematic diagram



MARKING: **B/5J**

ABSOLUTE MAXIMUM RATINGS ($T_a=25^\circ\text{C}$ unless otherwise noted)

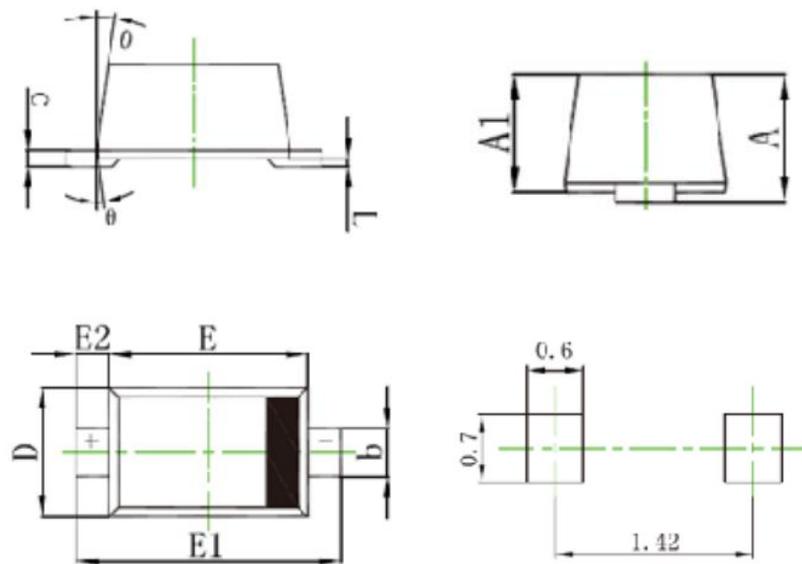
Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	V_{RRM}	30	V
DC Blocking Voltage	V_R	30	V
Continuous Forward Current	I_O	200	mA
Non-Repetitive Peak Forward Current *1	I_{FSM}	1	A
Power Dissipation	P_D	200	mW
Junction Temperature	T_J	125	°C
Storage Temperature	T_{STG}	-55 to +125	°C

*1 8.3 ms single half sine-wave

ELECTRICAL CHARACTERISTICS($T_a=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Type	Max	Unit
Breakdown Voltage	BV_R	$I_R = 100\mu\text{A}$	30			V
Forward Voltage	V_F	$I_F = 10\text{mA}$			0.40	V
		$I_F = 200\text{mA}$			0.40	V
Reverse Current	I_R	$V_R = 10\text{V}$			1	μA

SOD-523 Package Outline Dimensions



Symbol	Dimensions In Millimeters		
	Min	Typ	Max
A	0.51	-	0.77
A1	0.50	-	0.70
b	0.25	-	0.35
c	0.08	-	0.15
D	0.75	-	0.85
E	1.10	-	1.30
E1	1.50	-	1.70
E2	0.20REF.		
L	0.01	-	0.07
θ	7° REF.		